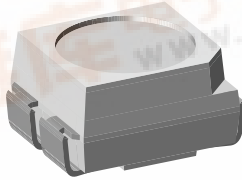




# VLMKE340.

Vishay Semiconductors

## Bicolor SMD LED PLCC-4



19211

### FEATURES

- SMD LED with exceptional brightness
- Multicolored
- Luminous intensity categorized
- EIA and ICE standard package
- Compatible with automatic placement equipment
- Suitable for IR reflow and TTW soldering
- Available in 8 mm tape
- Low profile package
- Non-diffused lens: excellent for coupling to light pipes and backlighting
- Low power consumption
- Luminous intensity ratio in one packaging unit  $I_{Vmax}/I_{Vmin} \leq 1.6$
- Lead (Pb)-free product - RoHS compliant - lead (Pb)-free soldering
- JEDEC level 2a



### DESCRIPTION

These devices have been designed to meet the increasing demand for surface mounting technology.

The package of the VLMKE340. is the PLCC-4.

It consists of a lead frame which is embedded in a white thermoplast. The reflector inside this package is filled up with clear epoxy.

This SMD device consists of a red and yellow chip. So it is possible to choose the color in one device.

### PRODUCT GROUP AND PACKAGE DATA

- Product group: LED
- Package: SMD PLCC-4
- Product series: bicolor
- Angle of half intensity:  $\pm 60^\circ$

### APPLICATIONS

- Automotive: backlighting in dashboards and switches
- Telecommunication: indicator and backlighting in telephone and fax
- Indicator and backlight for audio and video equipment
- Indicator and backlight in office equipment
- Flat backlight for LCDs, switches and symbols
- General use

PARTS TABLE		
PART	COLOR, LUMINOUS INTENSITY	TECHNOLOGY
VLMKE3400-GS08	Red/yellow, $I_V > 56$ mcd	AllnGaP on GaAs
VLMKE3400-GS18	Red/yellow, $I_V > 56$ mcd	AllnGaP on GaAs
VLMKE3401-GS08	Red/yellow, $I_V > 71$ mcd	AllnGaP on GaAs
VLMKE3401-GS18	Red/yellow, $I_V > 71$ mcd	AllnGaP on GaAs



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<b>ABSOLUTE MAXIMUM RATINGS<sup>1)</sup> VLMKE340.</b>				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage per diode <sup>2)</sup>	$I_R = 10 \mu\text{A}$	$V_R$	6	V
DC Forward current per diode	$T_{\text{amb}} \leq 80 \text{ }^\circ\text{C}$	$I_F$	30	mA
Surge forward current per diode	$t_p \leq 10 \mu\text{s}$	$I_{\text{FSM}}$	0.1	A
Power dissipation per diode		$P_V$	80	mW
Junction temperature		$T_j$	125	$^\circ\text{C}$
Operating temperature range		$T_{\text{amb}}$	- 40 to + 100	$^\circ\text{C}$
Storage temperature range		$T_{\text{stg}}$	- 40 to + 100	$^\circ\text{C}$
Thermal resistance junction/ ambient	mounted on PC board (pad size > 16 mm <sup>2</sup> )	$R_{\text{thJA}}$	560	K/W

Note:

<sup>1)</sup>  $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$ , unless otherwise specified

<sup>2)</sup> Driving the LED in reverse direction is suitable for short term application

<b>OPTICAL AND ELECTRICAL CHARACTERISTICS<sup>1)</sup> VLMKE340., RED</b>							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN	TYP.	MAX	UNIT
Luminous intensity	$I_F = 20 \text{ mA}$	VLMKE3400	$I_V$	56		180	mcd
		VLMKE3401	$I_V$	71		140	mcd
Dominant wavelength	$I_F = 20 \text{ mA}$		$\lambda_d$		630		nm
Peak wavelength	$I_F = 20 \text{ mA}$		$\lambda_p$		643		nm
Angle of half intensity	$I_F = 20 \text{ mA}$		$\varphi$		$\pm 60$		deg
Forward voltage	$I_F = 20 \text{ mA}$		$V_F$		1.9	2.6	V
Reverse voltage	$I_R = 10 \mu\text{A}$		$V_R$	6			V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$		$C_j$		15		pF

Note:

<sup>1)</sup>  $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$ , unless otherwise specified

<b>OPTICAL AND ELECTRICAL CHARACTERISTICS<sup>1)</sup> VLMKE340., YELLOW</b>							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN	TYP.	MAX	UNIT
Luminous intensity	$I_F = 20 \text{ mA}$	VLMKE3400	$I_V$	90		280	mcd
		VLMKE3401	$I_V$	112		224	mcd
Dominant wavelength	$I_F = 20 \text{ mA}$		$\lambda_d$	581	588	594	nm
Peak wavelength	$I_F = 20 \text{ mA}$		$\lambda_p$		590		nm
Angle of half intensity	$I_F = 20 \text{ mA}$		$\varphi$		$\pm 60$		deg
Forward voltage	$I_F = 20 \text{ mA}$		$V_F$		2	2.6	V
Reverse voltage	$I_R = 10 \mu\text{A}$		$V_R$	6			V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$		$C_j$		15		pF

Note:

<sup>1)</sup>  $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$ , unless otherwise specified



LUMINOUS INTENSITY CLASSIFICATION AND GROUP COMBINATIONS TLMKE34.. <sup>1)</sup>						
		RED				
		P2 56...71 mcd	Q1 71...90 mcd	Q2 90...112 mcd	R1 112...140 mcd	R2 140...180 mcd
YELLOW	Q2 90...112 mcd	00	00	00	00	00
	R1 112...140 mcd	00	00 01	00 01	00 01	00
	R2 140...180 mcd	00	00 01	00 01	00 01	00
	S1 180...224 mcd	00	00 01	00 01	00 01	00
	S2 224...280 mcd	00	00	00	00	00

Note:

<sup>1)</sup> followed by 00 or 01

COLOR CLASSIFICATION		
GROUP	DOMINANT WAVELENGTH (NM)	
	YELLOW	
	MAX	MAX
1	581	584
2	583	586
3	585	588
4	587	590
5	589	592
6	591	594

**TYPICAL CHARACTERISTICS**

T<sub>amb</sub> = 25 °C, unless otherwise specified

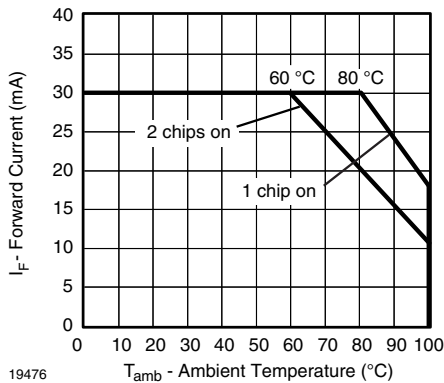


Figure 1. Forward Current vs. Ambient Temperature for InGaN

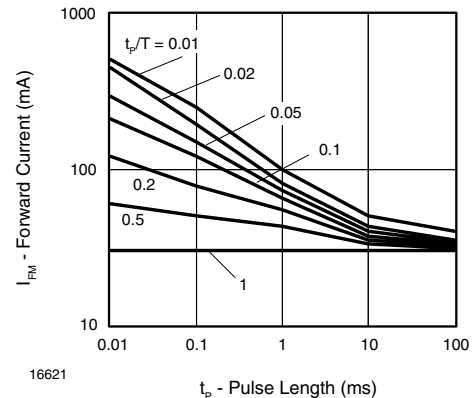


Figure 2. Forward Current vs. Pulse Duration

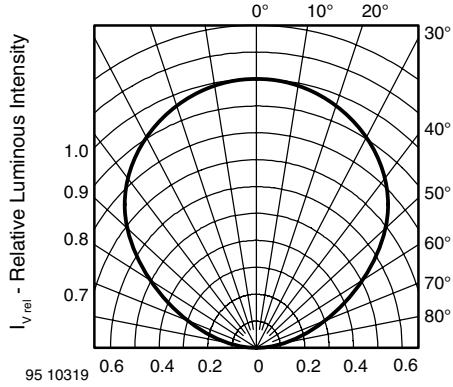


Figure 3. Rel. Luminous Intensity vs. Angular Displacement

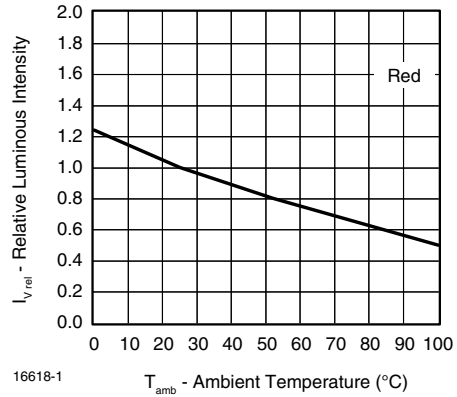


Figure 6. Rel. Luminous Intensity vs. Ambient Temperature

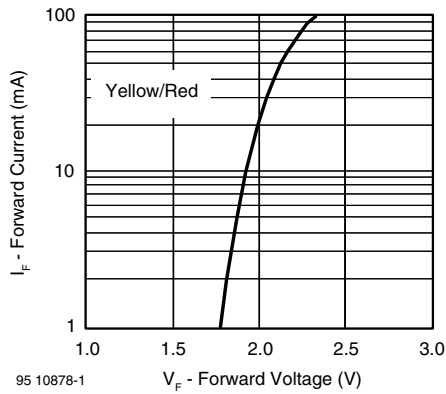


Figure 4. Forward Current vs. Forward Voltage

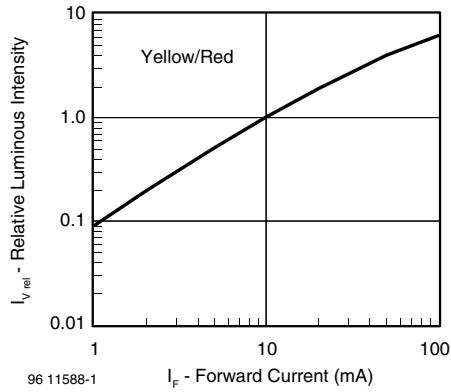


Figure 7. Relative Luminous Intensity vs. Forward Current

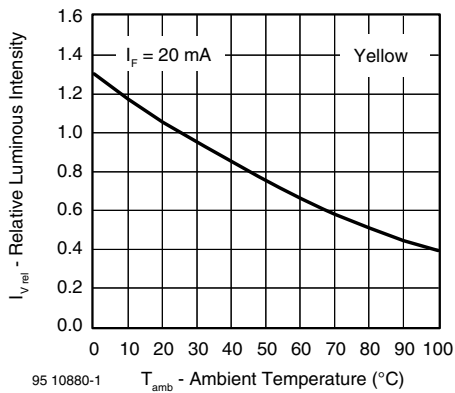


Figure 5. Rel. Luminous Intensity vs. Ambient Temperature

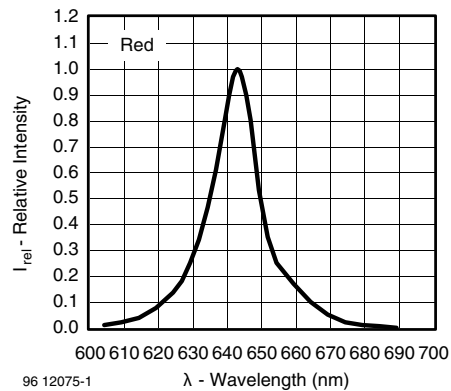


Figure 8. Relative Intensity vs. Wavelength

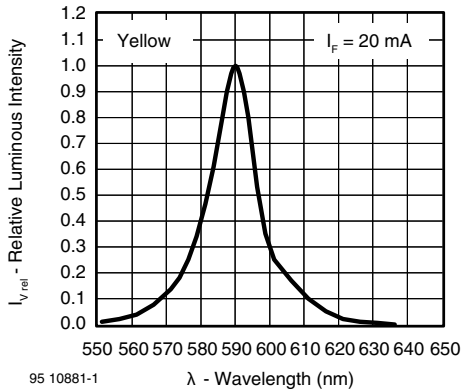


Figure 9. Relative Intensity vs. Wavelength

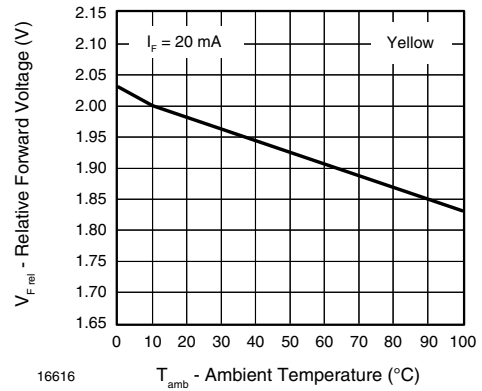


Figure 11. Relative Forward Voltage vs. Ambient Temperature

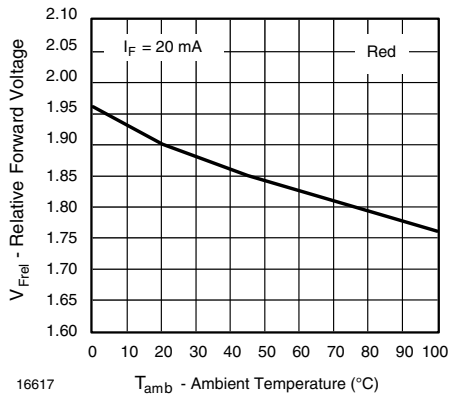
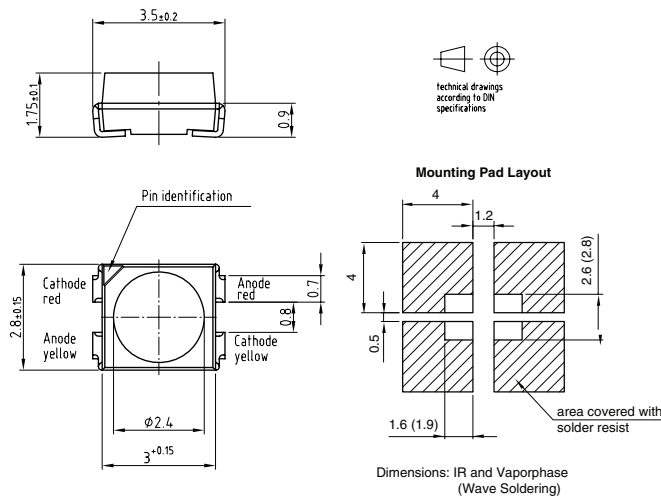


Figure 10. Relative Forward Voltage vs. Ambient Temperature

## PACKAGE DIMENSIONS in millimeters



Drawing-No: 6.541-5057.01-4  
Issue: 5; 30.05.07  
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# VLMKE340.

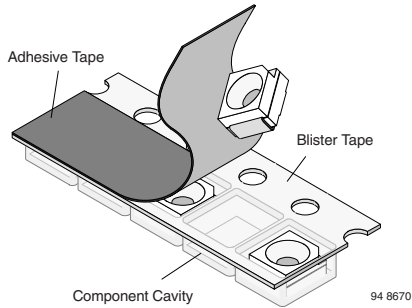
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## METHOD OF TAPING/POLARITY AND TAPE AND REEL

### SMD LED (VLM.3 - SERIES)

Vishay's LEDs in SMD packages are available in an antistatic 8 mm blister tape (in accordance with DIN IEC 40 (CO) 564) for automatic component insertion. The blister tape is a plastic strip with impressed component cavities, covered by a top tape.



### REEL PACKAGE DIMENSION IN MM FOR SMD LEDS, TAPE OPTION GS08 (= 1500 PCS.)

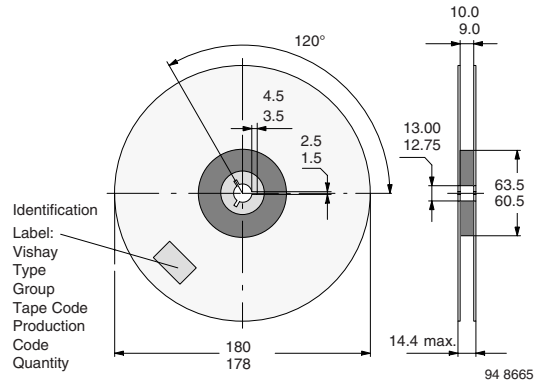


Figure 13. Reel dimensions - GS08

### TAPING OF VLM.3...

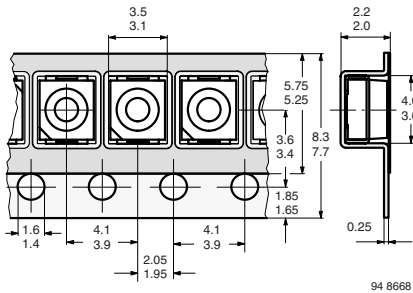


Figure 12. Tape dimensions in mm for PLCC-2

### REEL PACKAGE DIMENSION IN MM FOR SMD LEDS, TAPE OPTION GS18 (= 8000 PCS.) PREFERRED

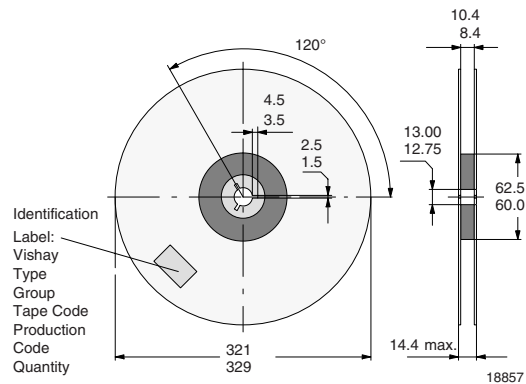


Figure 14. Reel dimensions - GS18



**SOLDERING PROFILE**

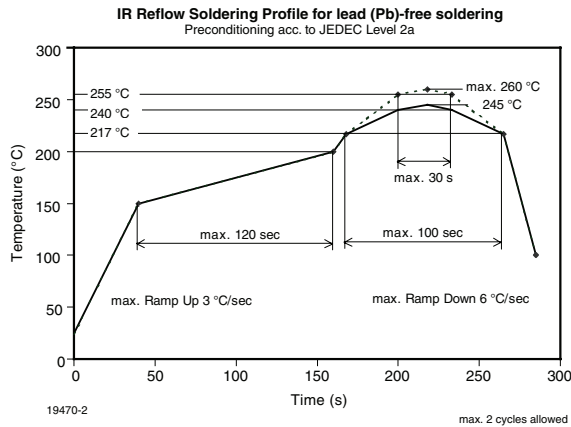


Figure 15. Vishay Lead (Pb)-free Reflow Soldering Profile (acc. to J-STD-020B)

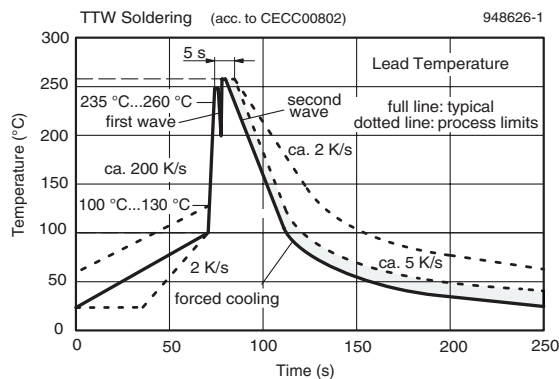
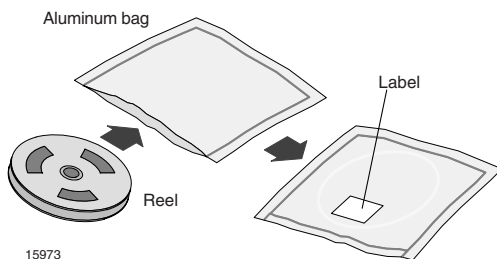


Figure 16. Double Wave Soldering of Opto Devices (all Packages)

**DRY PACKING**

The reel is packed in an anti-humidity bag to protect the devices from absorbing moisture during transportation and storage.



**FINAL PACKING**

The sealed reel is packed into a cardboard box. A secondary cardboard box is used for shipping purposes.

**RECOMMENDED METHOD OF STORAGE**

Dry box storage is recommended as soon as the aluminum bag has been opened to prevent moisture absorption. The following conditions should be observed, if dry boxes are not available:

- Storage temperature 10 °C to 30 °C
- Storage humidity ≤ 60 % RH max.

After more than 672 h under these conditions moisture content will be too high for reflow soldering.

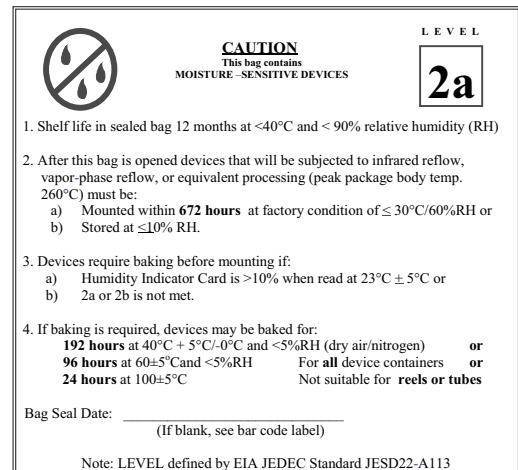
In case of moisture absorption, the devices will recover to the former condition by drying under the following condition:

192 h at 40 °C + 5 °C/ - 0 °C and < 5 % RH (dry air/nitrogen) or

96 h at 60 °C + 5 °C and < 5 % RH for all device containers or

24 h at 100 °C + 5 °C not suitable for reel or tubes.

An EIA JEDEC standard JESD22-A112 level 2a label is included on all dry bags.



Example of JESD22-A112 level 2a label

**ESD PRECAUTION**

Proper storage and handling procedures should be followed to prevent ESD damage to the devices especially when they are removed from the antistatic shielding bag. Electro-static sensitive devices warning labels are on the packaging.

**VISHAY SEMICONDUCTORS STANDARD BAR CODE LABELS**

The Vishay Semiconductors standard bar code labels are printed at final packing areas. The labels are on each packing unit and contain Vishay Semiconductors specific data.



### **OZONE DEPLETING SUBSTANCES POLICY STATEMENT**

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design  
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany





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